

PHOTOCOUPLER **PS2603,PS2604,PS2603L,PS2604L**

HIGH ISOLATION VOLTAGE, HIGH CTR 6-PIN PHOTOCOUPLER

-NEPOC[™] Series-

DESCRIPTION

The PS2603, PS2604, PS2604L are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon darington-connected phototransistor in a plastic DIP (Dual In-line Package).

The PS2603L, PS2604L are lead bending type (Gull-wing) for surface mount.

FEATURES

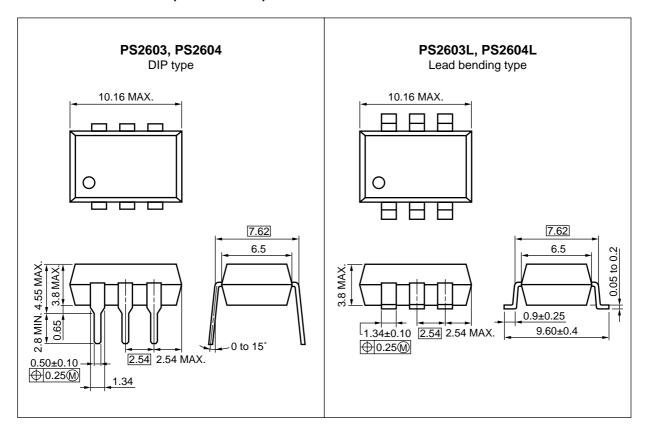
- High Isolation voltage (BV = 5 000 Vr.m.s.)
- High-speed switching (t_r , $t_f = 100 \mu s$ TYP.)
- High current transfer ratio (CTR = 2 000 % TYP.)
- UL approved: File No. E72422 (S)
- Ordering number of taping product: PS2603L-E3, E4, PS2604L-E3, E4

★ APPLICATIONS

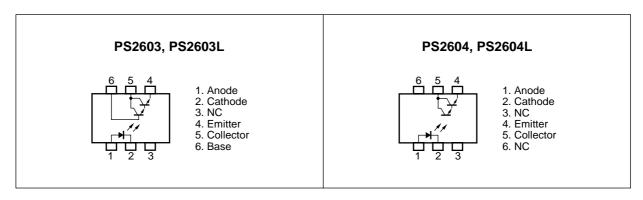
- Power supply
- Telephone
- · AC/DC line interface
- Electric home appliances

The information in this document is subject to change without notice.

★ PACKAGE DIMENSIONS (in millimeters)



PIN CONNECTIONS (TOP VIEW)



ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	80	mA
	Reverse Voltage	VR	6.0	V
	Power Dissipation Derating	∆P₀/°C	1.5	mW/°C
	Power Dissipation	PD	150	mW
	Peak Forward Current ¹	IFP	1	Α
Transistor	Collector to Emitter Voltage	Vceo	40	V
	Emitter to Collector Voltage	Veco	6	V
	Collector Current	lc	200	mA
	Power Dissipation Derating	∆Pc/°C	2.0	mW/°C
	Power Dissipation	Pc	200	mW
Isolation Voltage ²		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	−55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1 %

^{*2} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

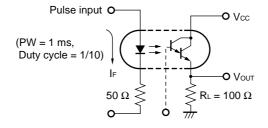
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.1	1.4	V
	Reverse Current	lR	V _R = 5 V			5.0	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		30		pF
Transistor	Collector to Emitter Dark Current	Iceo	Vce = 40 V, IF = 0 mA			400	nA
	DC Current Gain*1	hfe	Ic = 2 mA, VcE = 5 V		180		
Coupled	Current Transfer Ratio (Ic/IF)*2	CTR	I _F = 1 mA, V _{CE} = 2 V	200	2 000		%
	Collector Saturation Voltage	VCE (sat)	I _F = 1 mA, I _C = 2 mA			1.0	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVpc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.6		pF
	Rise Time *3	t r	$Vcc = 5 \text{ V, Ic} = 10 \text{ mA, RL} = 100 \Omega$		100		μs
	Fall Time ^{*3}	tr			100		

*1 Second stage transistor (PS2603, PS2603L only)

*2 CTR rank

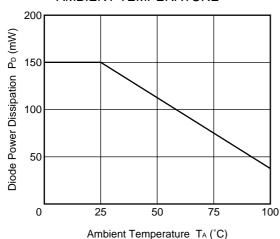
K: 2 000 to (%) L: 700 to 3 400 (%) M: 200 to 1 000 (%)

*3 Test circuit for switching time

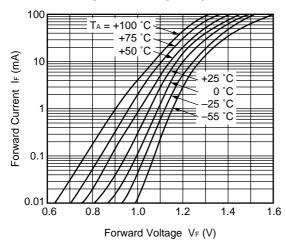


TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

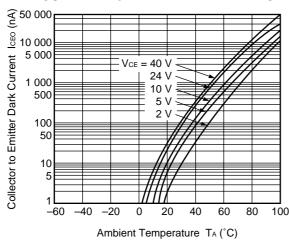




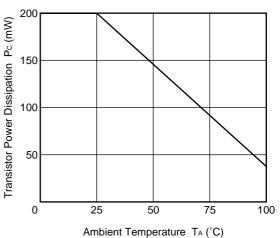
FORWARD CURRENT vs. FORWARD VOLTAGE



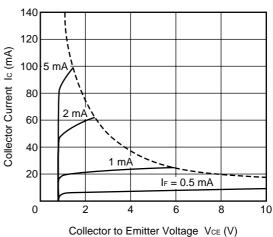
COLLECTOR TO EMITTER DARK **CURRENT vs. AMBIENT TEMPERATURE**



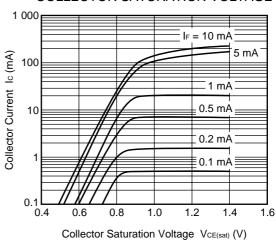
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



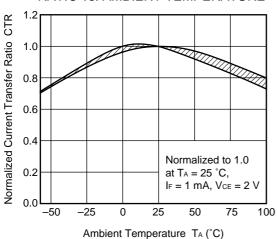
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



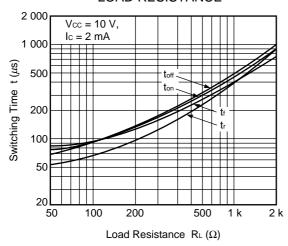
COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**



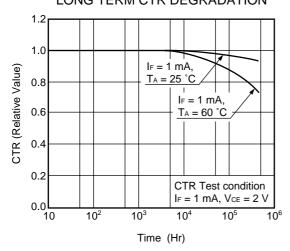
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

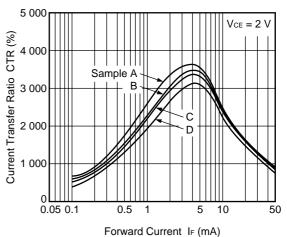


LONG TERM CTR DEGRADATION

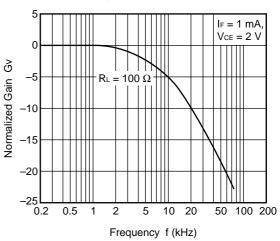


Remark The graphs indicate nominal characteristics.

CURRENT TRANSFER RATIO vs. FORWARD CURRENT



FREQUENCY RESPONSE



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

• Peak reflow temperature 235 °C (package surface temperature)

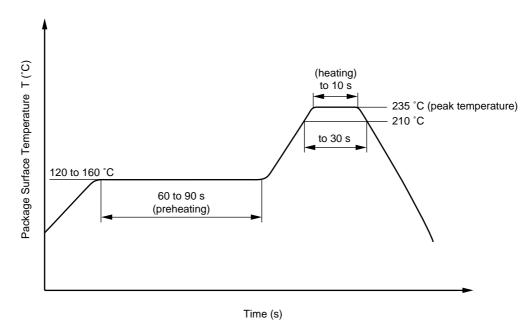
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Three

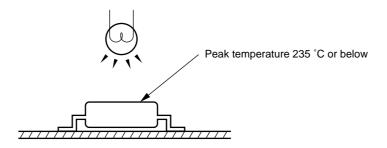
• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



Caution Please avoid removing the residual flux by water after the first reflow process.



(2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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Anti-radioactive design is not implemented in this product.

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